

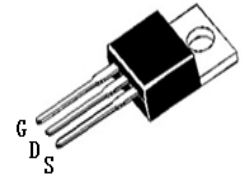
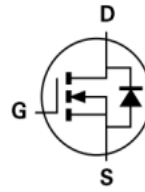


# N-Channel Enhancement Mode Power MOSFET

## RY4N60

### MAIN CHARACTERISTICS

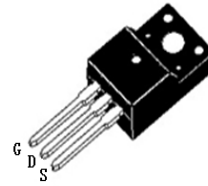
$I_D$	4A
$V_{DSS}$	600V
$R_{DS(on)-max}$ (@ $V_{GS}=10V$ )	2.4 $\Omega$
$Q_G$ -typ	15nC



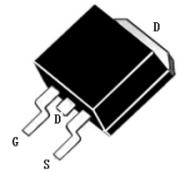
RYF4N60C/TO-220C

### FEATURES

- Fast Switching
- Low ON Resistance
- Low Gate Charge
- 100% Single Pulse avalanche energy Test



RYF4N60F/TO-220F



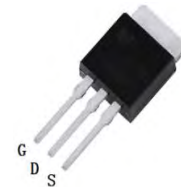
RY4N60A3/TO-263

### APPLICATIONS

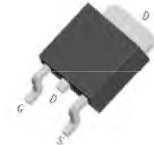
- Power switch circuit of adaptor and charger.

### MECHANICAL DATA

- Case: Molded plastic
- Mounting Position: Any
- Molded Plastic: UL Flammability Classification Rating 94V-0
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Solder bath temperature 275 $^{\circ}C$  maximum, 10s per JESD 22-B106



RY4N60A1/TO-251



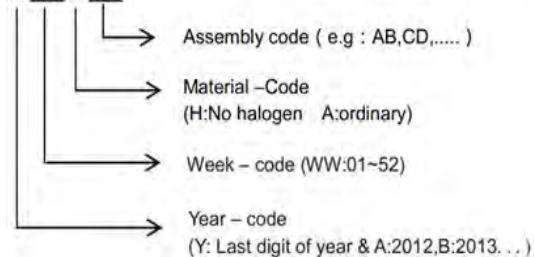
RY4N60A2/TO-252

### Marking on the body



#### MAKING:

X X X X X X



### Ordering information

Part Number	Package	Unit Weight	Base Quantity	Delivery mode
RYF4N60C	TO-220C	0.07oz(1.96g)	50 pcs / tube	1Kpcs/box 5Kpcs/carton
RYF4N60F	TO-220F	0.06oz(1.74g)	50 pcs / tube	1Kpcs/box 5Kpcs/carton
RY4N60A3	TO-263	0.04oz(1.16g)	50 pcs / tube	1Kpcs/box 5Kpcs/carton
RY4N60A3	TO-263	0.04oz(1.16g)	800 pcs / reel	800pcs/box 4Kpcs/carton
RY4N60A1	TO-251	--	--	--
RY4N60A2	TO-252	0.011oz(0.32g)	2500 pcs / reel	2.5Kpcs/box 12.5Kpcs/carton



# N-Channel Enhancement Mode Power MOSFET

## RY4N60

### Maximum Ratings at Tc=25°C unless otherwise specified

Characteristics	Symbol	Value			Unit
		220C/263	220F	251/252	
Drain-Source Voltage	$V_{DS}$	600			V
Gate-Source Voltage	$V_{GS}$	±30			V
Continue Drain Current	$I_D$	4			A
Pulsed Drain Current (Note1)	$I_{DM}$	16			A
Power Dissipation	$P_D$	82	33	82	W
Single Pulse Avalanche Energy (Note1)	$E_{AS}$	250			mJ
Operating Temperature Range	$T_J$	150			°C
Storage Temperature Range	$T_{STG}$	-55 to +150			°C
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.67	4.17	1.67	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	100	62.5	100	°C/W

Note1:Pulse test: 300 μs pulse width, 2 % duty cycle

### Electrical Characteristics at Tc=25°C unless otherwise specified

Characteristics	Test Condition	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	$BV_{DSS}$	600	-	-	V
Drain-Source Leakage Current	$V_{DS} = 600 V, V_{GS} = 0 V$	$I_{DSS}$	-	-	1	μA
Gate Leakage Current	$V_{GS} = \pm 30 V, V_{DS} = 0 V$	$I_{GSS}$	-	-	±100	nA
Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	$V_{GS(th)}$	2	-	4	V
Drain-Source On-State Resistance	$V_{GS} = 10 V, I_D = 2 A$	$R_{DS(on)}$	-	-	2.4	Ω
Forward Transconductance	$V_{DS} = 15 V, I_D = 2 A$	$g_{fs}$	-	3.5	-	S
Input Capacitance	$V_{GS} = 0 V, V_{DS} = 25 V,$ $f = 1 MHz$	$C_{iss}$	-	590	-	pF
Output Capacitance		$C_{oss}$	-	55	-	pF
Reverse Transfer Capacitance		$C_{rss}$	-	4	-	pF
Turn-on Delay Time(Note2)	$I_D = 4 A, V_{DD} = 300V,$ $R_G = 10 \Omega$	$t_{d(ON)}$	-	14	-	ns
Rise Time(Note2)		$t_r$	-	15	-	ns
Turn-Off Delay Time(Note2)		$t_{d(OFF)}$	-	34	-	ns
Fall Time(Note2)		$t_f$	-	13	-	ns
Total Gate Charge(Note2)	$I_D = 4 A, V_{DD} = 480 V,$ $V_{GS} = 10 V$	$Q_G$	-	15	-	nC
Gate to Source Charge(Note2)		$Q_{GS}$	-	3	-	nC
Gate to Drain Charge(Note2)		$Q_{GD}$	-	7	-	nC

### Source-Drain Diode Characteristics at Ta=25°C unless otherwise specified

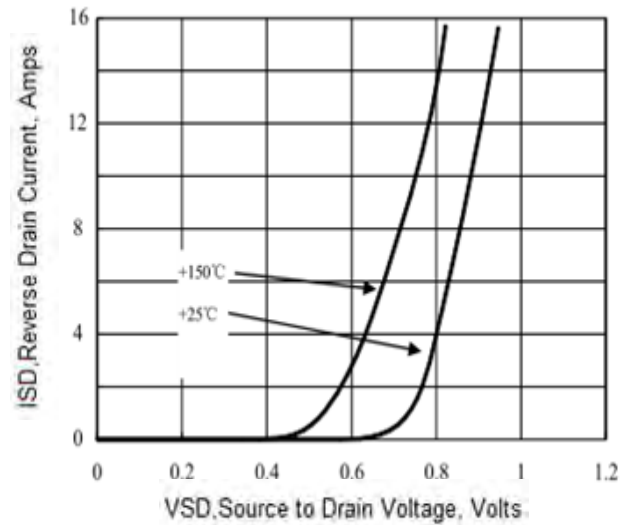
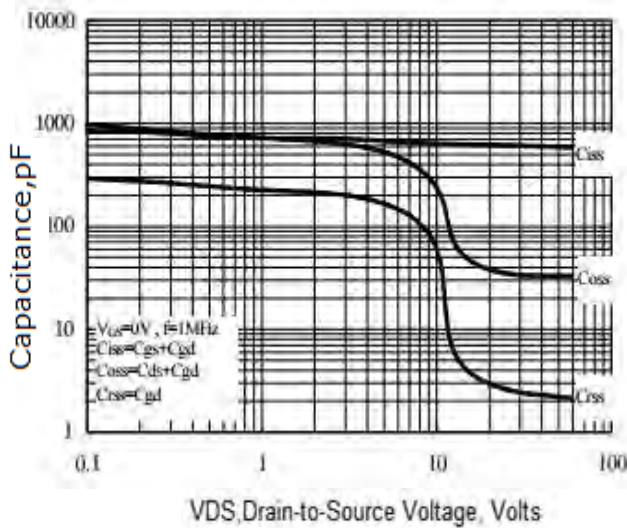
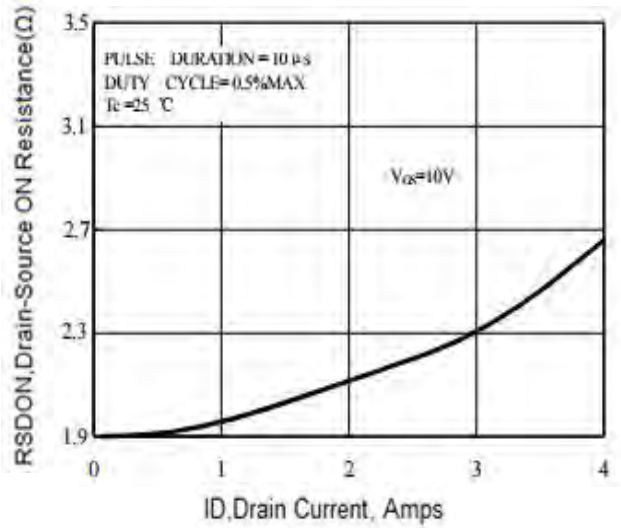
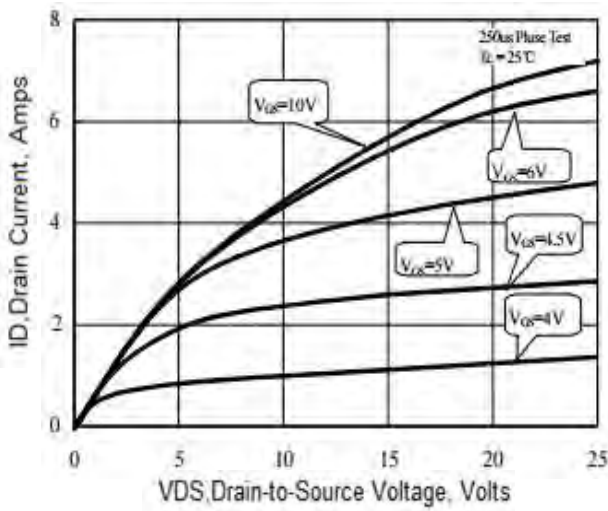
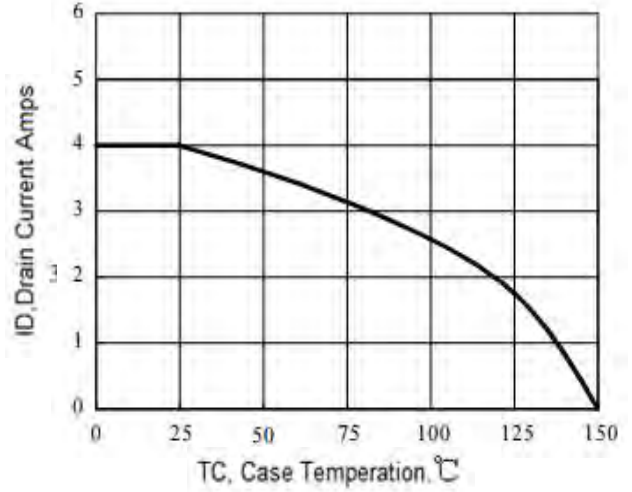
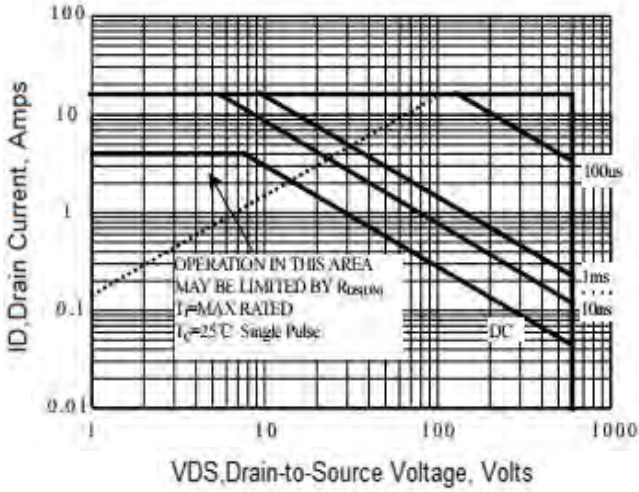
Characteristics	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Maximun Body-Diode Continuous Current		$I_S$	-	-	4	A
Maximun Body-Diode Pulsed		$I_{SM}$	-	-	16	A
Drain-Source Diode Forward Voltage	$I_{SD} = 4 A$	$V_{SD}$	-	-	1.4	V
Reverse Recovery Time(Note2)	$I_{SD} = 4 A, V_{GS} = 0 V,$ $di_F / dt = 100 A/\mu s$	$t_{rr}$	-	250	-	ns
Reverse Recovery Charge(Note2)		$Q_{rr}$	-	1	-	μC

Note2:Pulse test: 300 μs pulse width, 2 % duty cycle



# RY4N60

## RATINGS AND CHARACTERISTIC CURVES

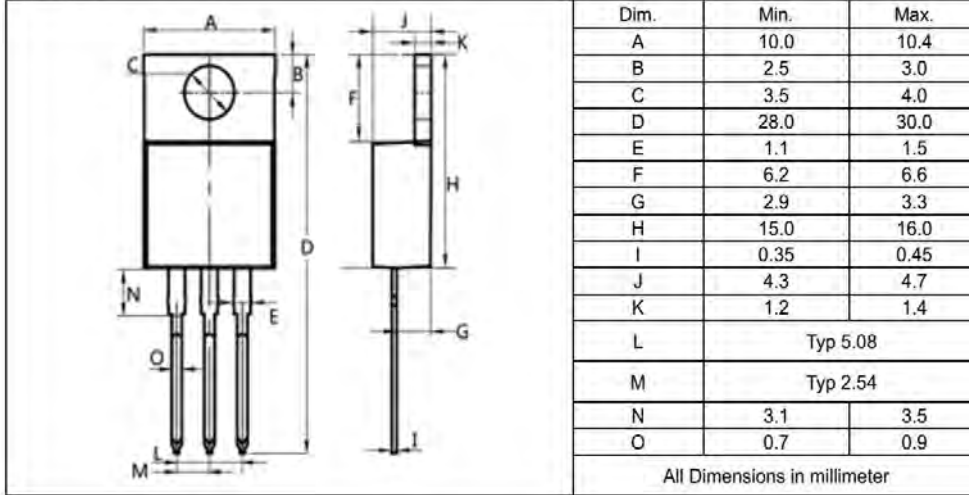




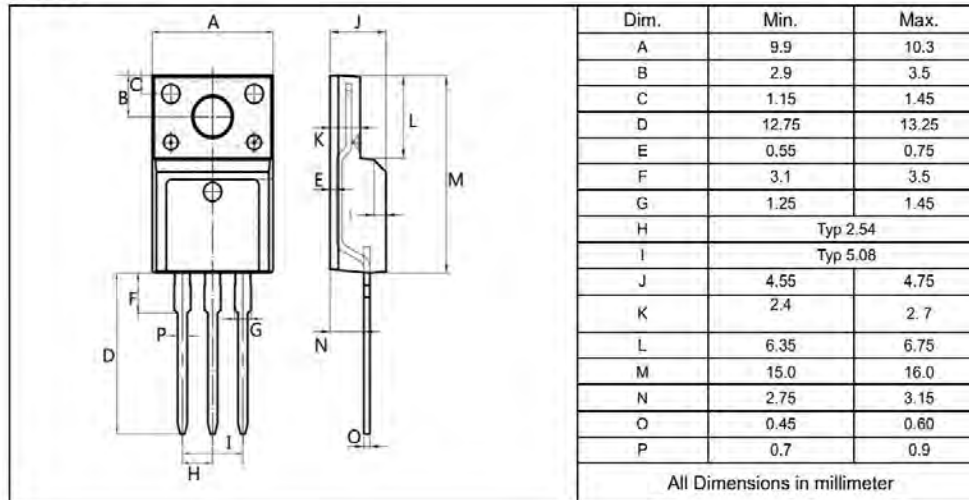
# RY4N60

Package Outline Dimensions millimeters

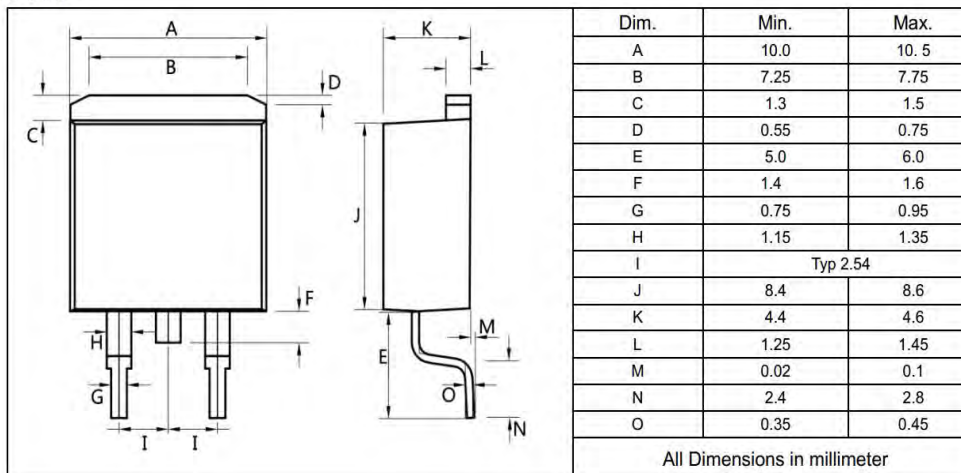
TO-220AB



TO-220F



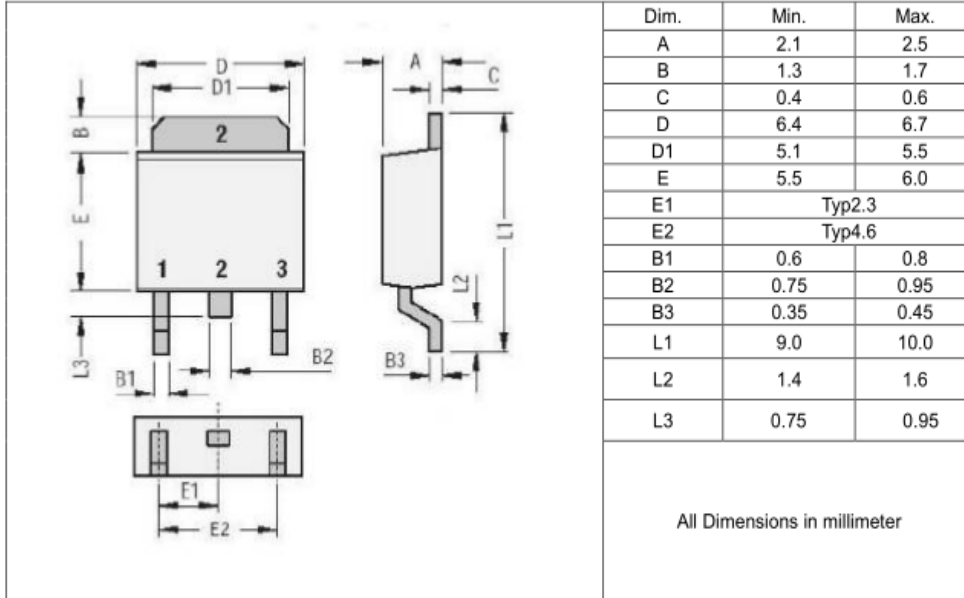
TO-263



# RY4N60

Package Outline Dimensions millimeters

TO-252



TO-251

